

#### HSTD14

14th international "Hiroshima" Symposium on the Development and Application of Semiconductor Tracking Detectors

> November 19<sup>th</sup>, 2025 Taipei, Taiwan

# Towards a 20 ps timing detector with hybrid and CMOS monolithic LGADs for the future ALICE 3 experiment at LHC





#### **Sofia Strazzi**

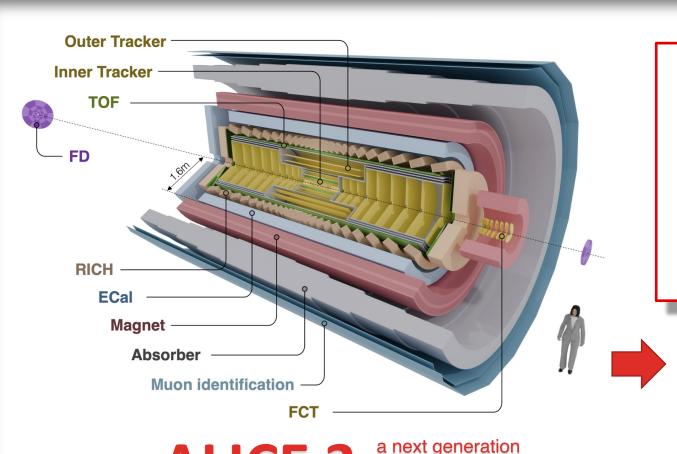
on behalf of the ALICE Collaboration

University and INFN Bologna, Italy



# The ALICE Collaboration has submitted the proposal for a next-generation heavy-ion experiment, ALICE 3, to be installed at the LHC during the LS4 (2034-35)





New, compact, low-mass, experimental apparatus totally based on the most advanced silicon technologies

Letter of Intent: https://arxiv.org/abs/2211.02491 Scoping Document: https://cds.cern.ch/record/2925455

New exciting opportunities for the study of:

- → Multi-charm hadrons at low momenta: Crucial test for models for baryon production models
  - ◆ EM radiation produced in the first evolution phases of Quark Gluon Plasma (QGP)

| 2028 | 2029 | 2030 | 2031 | 2032 | 2033 | 2034 | 2035 | **2036 - 2041** |

LHC LS3 LHC Run 4 LHC LS4 LHC Run 5

2026

2027

The ALICE Collaboration has submit experiment, ALICE 3, to be in



#### **Time-Of-Flight System (TOF)**

- inner TOF R ≈ 19 cm
- outer TOF R ≈ 85 cm
- forward TOF z ≈ 375 cm

 $\begin{array}{c} \text{Separation} \propto \frac{L}{\sigma_{\text{\tiny TOF}}} \end{array}$ 

#### **Requirements:**

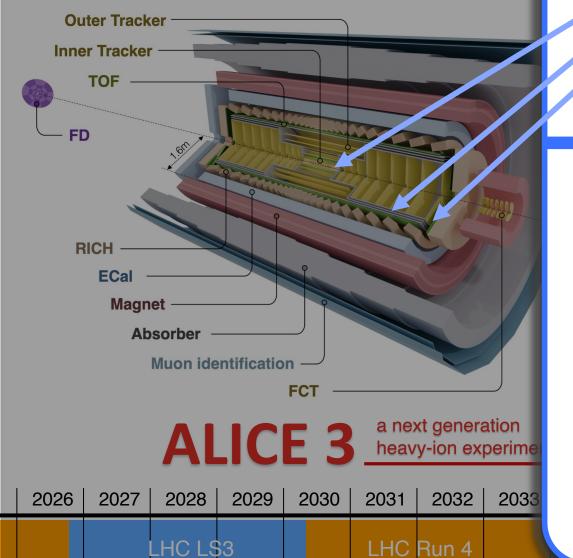
- Moderate rad.  $\begin{cases} \text{inner TOF: NIEL} \sim 6.1 \cdot 10^{12} \text{ 1-MeV } n_{eq} \text{ /cm}^2 \\ \text{outer TOF: NIEL} \sim 9 \cdot 10^{11} \text{ 1-MeV } n_{eq} \text{ /cm}^2 \\ \text{forward TOF: NIEL} \sim 8.5 \cdot 10^{12} \text{ 1-MeV } n_{eq} \text{ /cm}^2 \end{cases}$
- Low material budget ~1-3% X<sub>0</sub>



e/π ≤ 500 MeV/c K/π ≤ 2.5 GeV/c p/K ≤ 4 GeV/c 20ps

Extensive R&D on the most advanced silicon technologies:

LGADs, SiPMs, CMOS-LGADs



rst

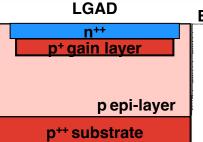
#### **MOTIVATIONS - LOW GAIN AVALANCHE DETECTOR (LGAD)**





n<sup>++</sup> p epi-layer

p<sup>++</sup> substrate



Electric field

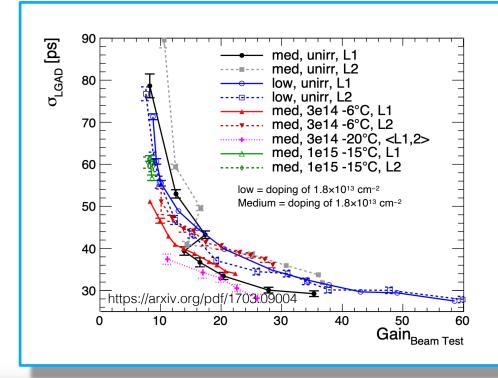
Gain region: very high electric field

Drift region: low and uniform electric field

Internal low-gain multiplication mechanism

#### Optimized to obtain:

- Fast signal (dV/dt)
- Improved S/N
- Excellent timing performance



State-of-the-art LGAD (35-50 µm-thick)

→ ~30 ps

Already used or envisioned for detector upgrades at the HL-LHC (e.g. ATLAS and CMS) for 2026

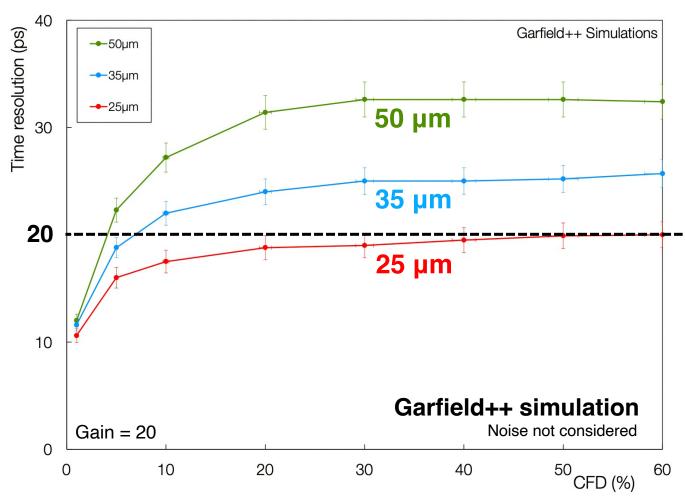
#### MOTIVATIONO

#### TE DETECTOR (LGAD)

<L1,2>

ain<sub>Beam Test</sub>





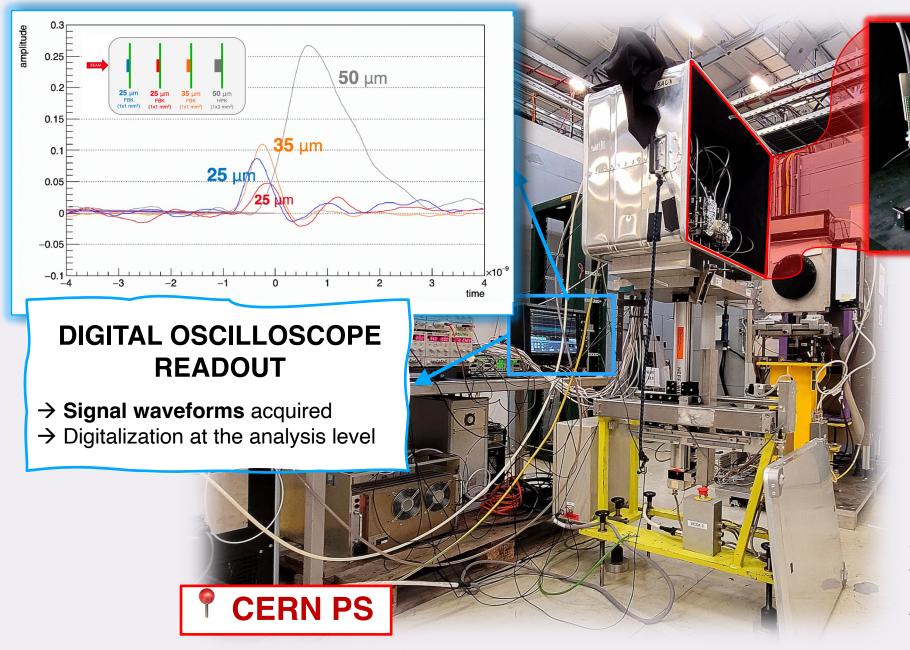
→ Potential of a thinner layout of LGAD

ALICE 3 TOF detector needs an even better time resolution

→ 20 ps

State-of-tile-art LGAD (35-5  $\mu$ m-thick)  $\rightarrow$  ~30 ps

Already used or envisioned for detector upgrades at the HL-LHC (e.g. ATLAS and CMS) for 2026

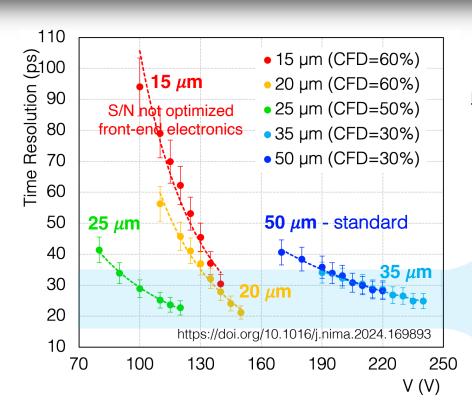




Seven beam test campaigns (2021-2024) with a hadron beam of  $p\sim10$ -12 GeV/c

#### **TEST OF THE FIRST VERY THIN LGAD PROTOTYPES**



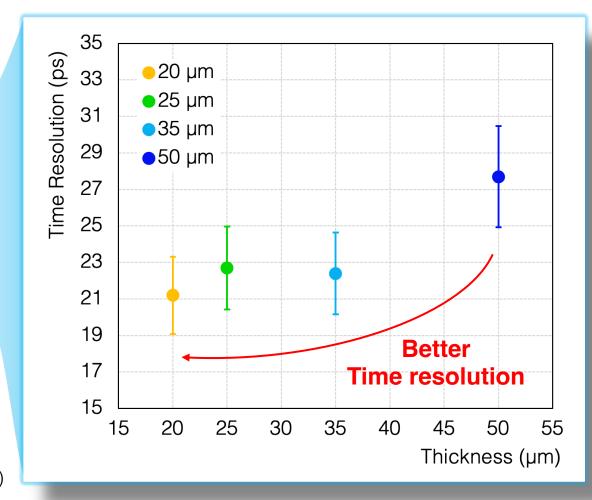


#### ♦ 50 μm in line with the expectations

- > Validation of setup and analysis procedure
- → Improved time res. with thinner LGADs
  - > All in agreement with the MC simulation
  - > Slightly worse for the 25 μm due to worse S/N (very high doping due to a problem in the wafer production)

# First 15, 20, 25 and 35 μm thick FBK LGADs were tested in a beam test

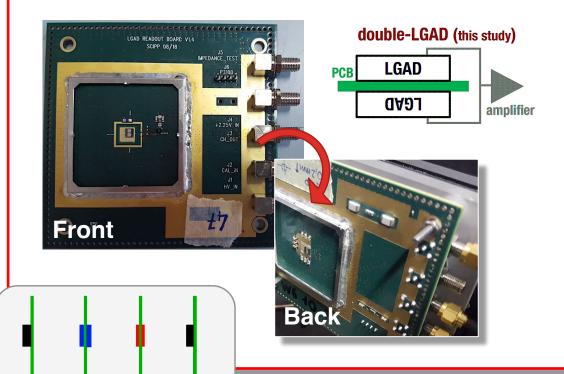
https://link.springer.com/article/10.1140/epjp/s13360-022-03619-1







Two uniform LGADs attached to the two sides of the same board, **both** connected to the same amplifier

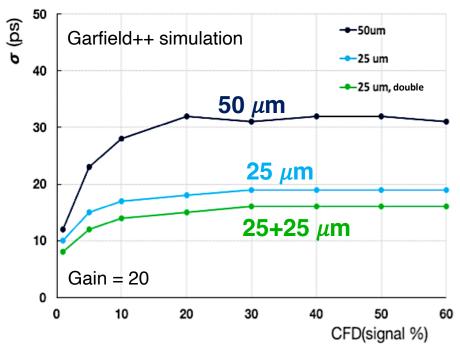


Ref-35μm 15+15μm 20+20μm Ref-25μm FBK FBK FBK FBK FBK (1x1 mm²) (1.3x1.3 mm²)(1.3x1.3 mm²) (1x1 mm²)

#### Higher signal

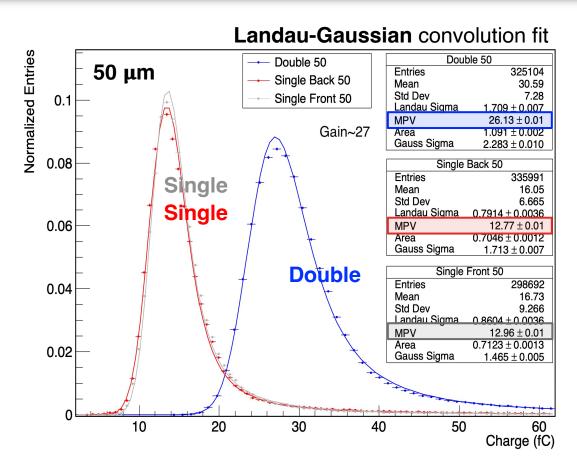
- → Less power-consuming front-end electronics
- → Electronics similar to the one used for the standard LGADs (50 μm)

#### Better time resolution

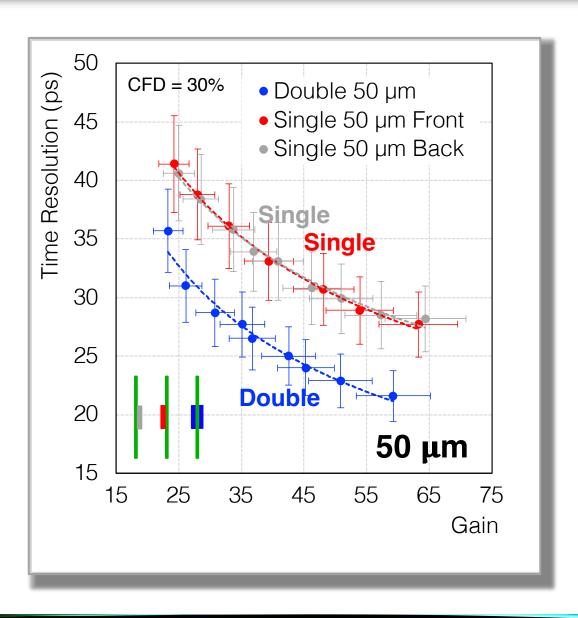


#### **DOUBLE-LGAD TEST BEAM RESULTS**



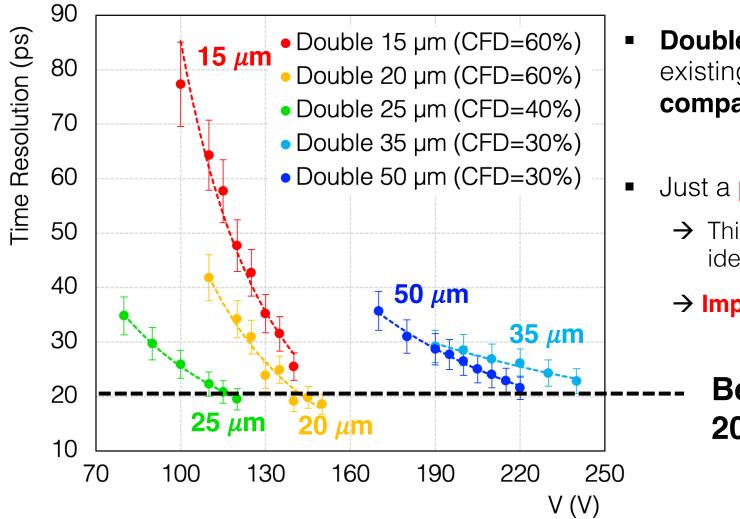


- Double charge
  - → Big advantage for the electronics
- Better time resolution for the double-LGAD





#### Timing performances Single VS Double-LGAD



- Double-50 μm (already existing technology)
   compatible with 20 ps
- Just a proof of concept:
  - → Thinner prototypes not perfectly identical within the couples
  - → Improvement expected

Below 20 ps

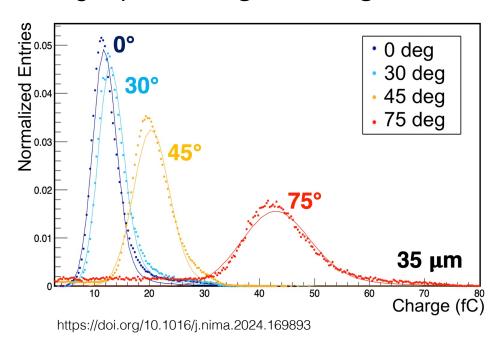
#### PERFORMANCES WITH INCLINED TRACKS

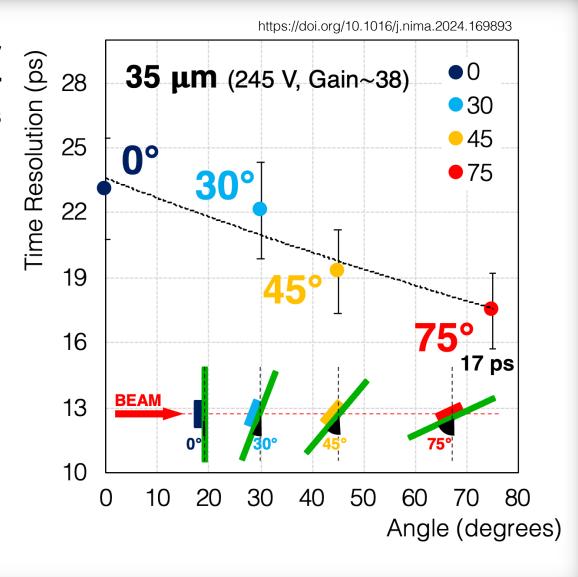


#### TOF track incidence angles [0°, 74.6°]

The **time resolution** slightly **improves** going to **higher** impinging **angles** 

#### Longer path → **higher charge** release



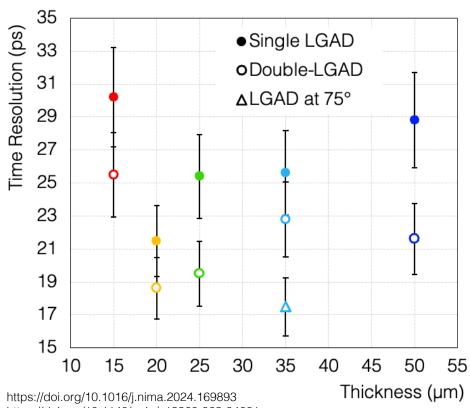




#### **HYBRID LGAD**

Outstanding performances in different layouts and implementations

Time res. in line with the needs of ALICE 3 TOF

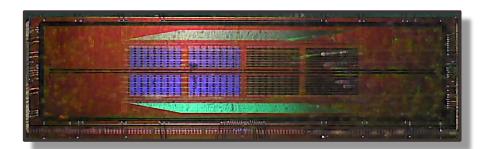


https://doi.org/10.1016/j.nima.2024.169893 https://doi.org/10.1140/epjp/s13360-023-04621-x https://doi.org/10.1016/j.nima.2024.169893

#### **CMOS-LGAD**

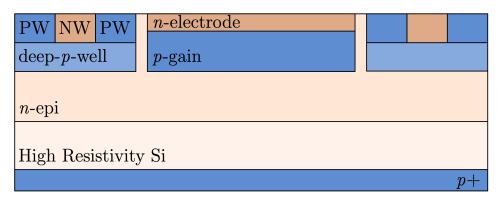
Combining the LGAD principle with a monolithic approach can provide:

Lower material budget and costs
Simpler and cheaper assembly



→ Baseline solution

#### **CMOS-LGAD**



Produced by LFoundry standard 110 nm CMOS process, within the INFN ARCADIA project

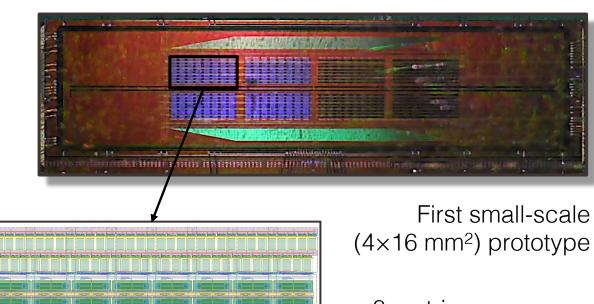
# Adding a p-gain layer below the collecting electrode

- V<sub>top</sub> to control the gain
- V<sub>back</sub> to deplete the sensor

Front-end electronics: cascoded common source architecture with split bias current and active load



# MadPix: Monolithic CMOS Avalanche Detector PIXelated Prototype for ps timing applications

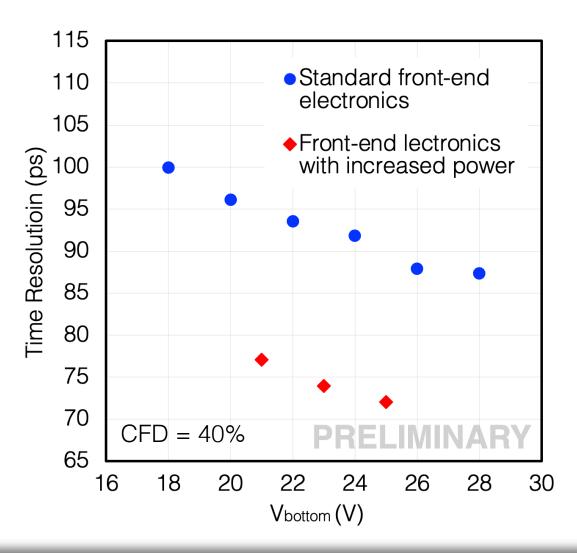


- 8 matrices
- 64 pixels per matrix
- A<sub>pixel</sub>=250×100 μm<sup>2</sup>

#### TIME RESOLUTION OF CMOS-LGADS

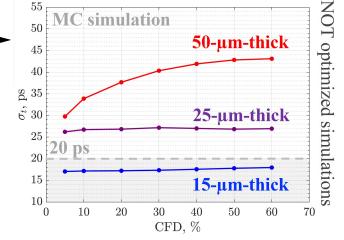


#### First 48 μm-thick CMOS-LGADs (gain ≈ 7-11) were tested in a beam test



- Time res. ≈ 88 ps (Front-end electronics in standard conditions + Sensor)
- ◆ Time res. of the sensor with increased power on the front-end electronics < 75 ps</p>



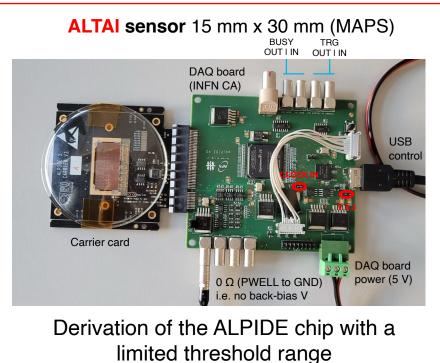






#### **TEST BEAM WITH A** TRACKING TELESCOPE

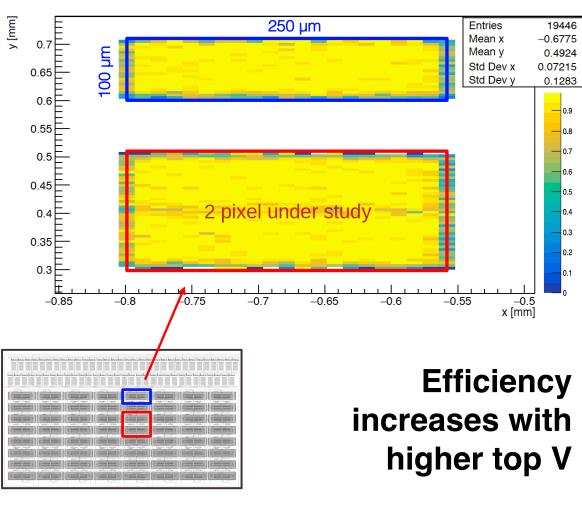
- **→ Efficiency** map
- **→ Time resolution** vs impinging position correlation



 $\sim$  3-5  $\mu$ m of tracking resolution expected on the DUTs

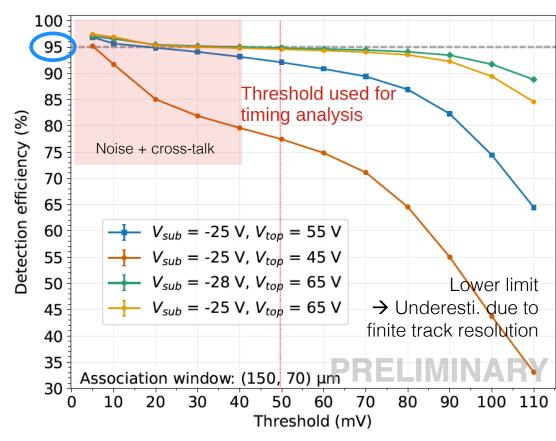
#### **CMOS-LGAD EFFICIENCY**





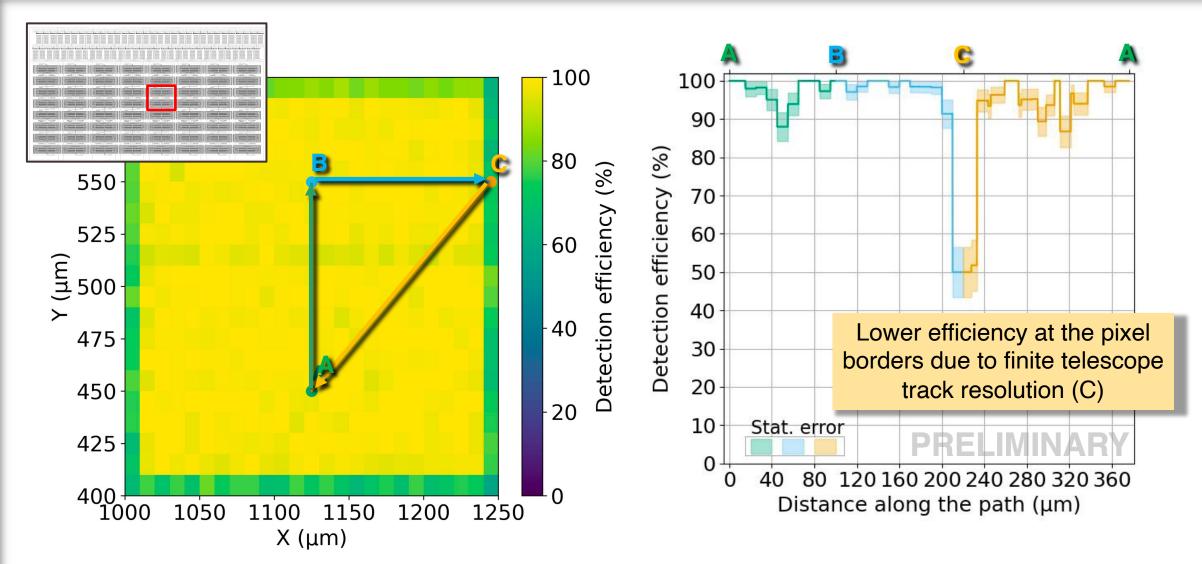
#### (Electronics noise: 1mV, cross-talk <20ps)

# Global efficiency VS threshold



#### **CMOS-LGAD EFFICIENCY**

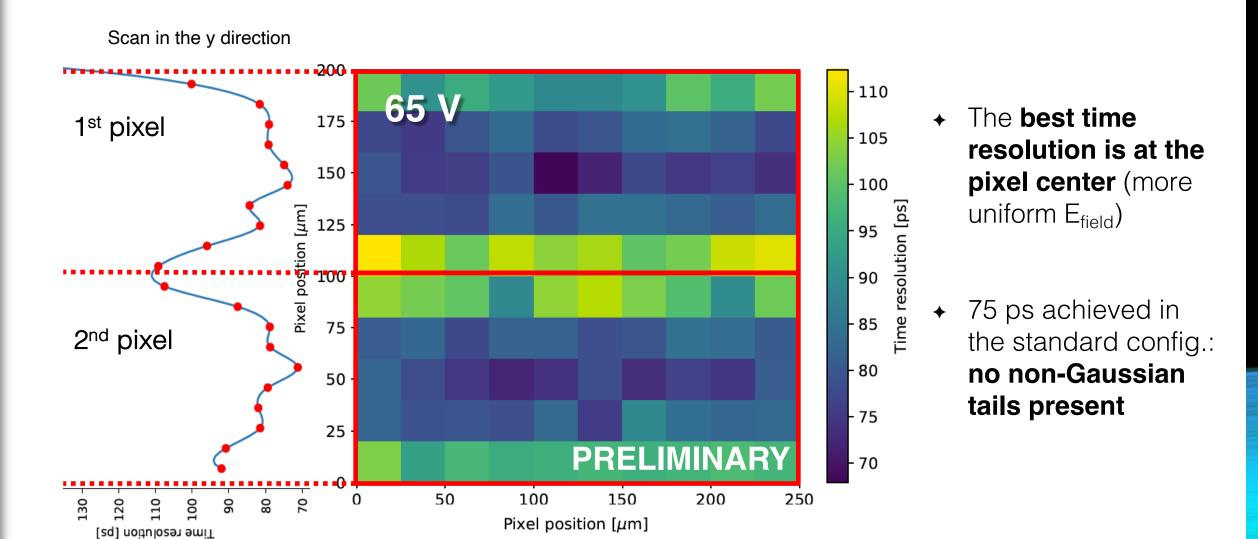




No significant efficiency drop between pixels (at  $V_{top}$ : 65V)

#### **CMOS-LGAD TIME RESOLUTION**







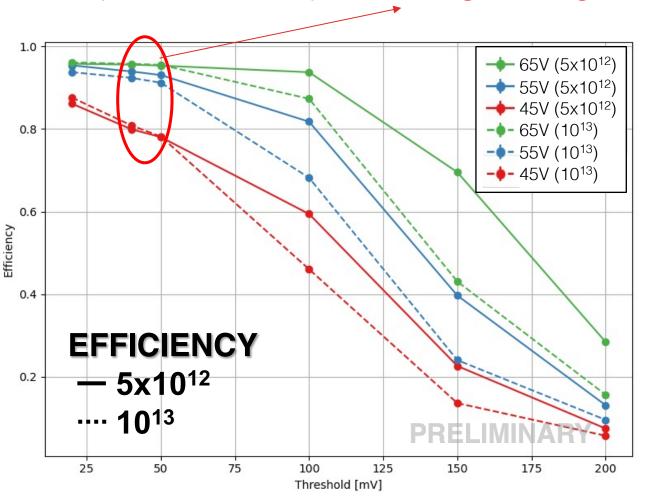
#### **IRRADIATION CAMPAIGN**

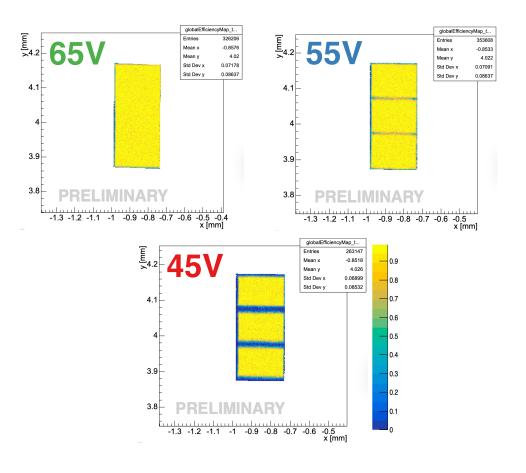


5 different fluences --- 5×10<sup>12</sup>, 10<sup>13</sup>, 5×10<sup>13</sup>, 10<sup>14</sup>, 10<sup>15</sup> MeV n<sub>eq</sub>/cm<sup>2</sup>

\*REQUIREMENT FOR ALICE3 TOF

#### Compatible efficiency and no sign of degradation with irradiation





#### CONCLUSIONS



#### **→ Hybrid LGADs**

The R&D campaign resulted in sensors with a time resolution in line with the needs of ALICE 3 TOF

**20** ps achieved across different layouts and tested implementations

**✗** Solid backup solution

#### **♦ CMOS-LGADs**

Time resolution in line with the simulations, and efficiency >95%

# **75** ps → current performance for CMOS sensors

From simulation, thinner sensors with a higher gain are expected to reach better results in line with the ALICE 3 TOF

Many ongoing studies to fully unlock the potential of these technologies

# BACKUP SLIDES BACKUP SLIDES

#### **ACKNOWLEDGEMENTS**

The measurements leading to these results have been performed at the Test Beam Facility at DESY Hamburg (Germany), a member of the Helmholtz Association (HGF).

The research leading to these results has received funding from the European Union's Horizon Europe research and innovation programme under grant agreement no.101057511.

#### **TESTED DETECTORS**



15 μm & 20 μm-thick FBK LGADs

**10 prototypes** from EXFLU1 production

Area =  $1.3x1.3 \text{ mm}^2$ 

50 μm-thick HPK LGADs

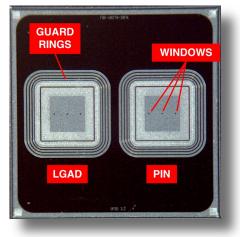
**5 sensors** from HPK2 production

Area =  $1.3x1.3 \text{ mm}^2$ 



# First very thin LGAD prototypes produced by FBK with different

- Size
- Geometry
- Inter-pad config.



25 μm & 35 μm-thick FBK LGADs

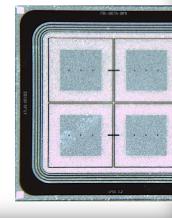
**40 prototypes** from UFSD3.2 production

Area =  $1x1 \text{ mm}^2$ 

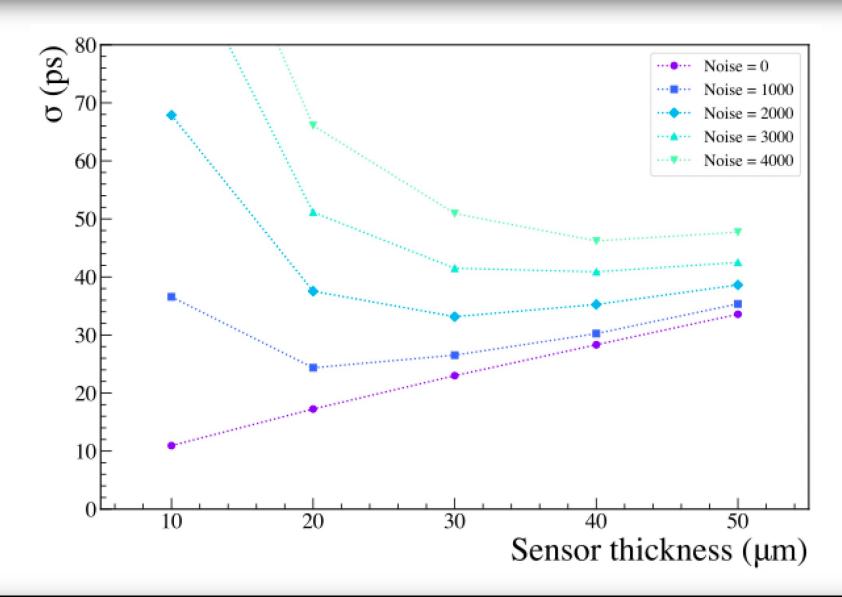
Difficulties in the production:

25 μm: highly doped 35 μm: type inversion

Matrices with different interpad designs

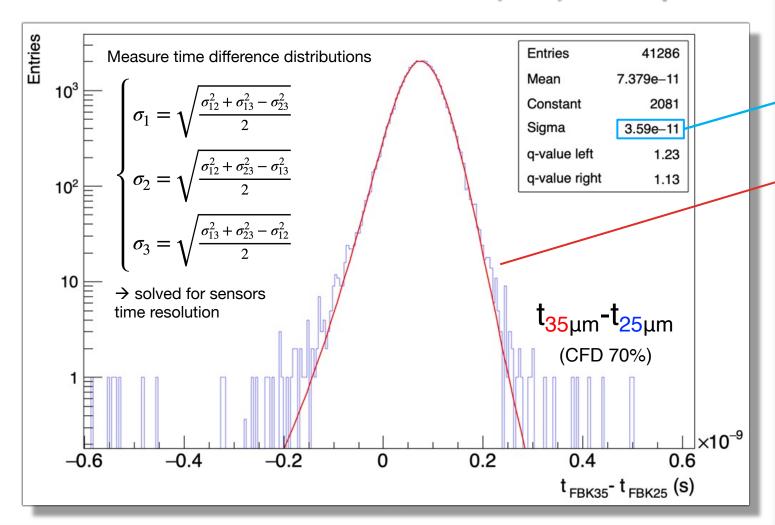


### SIMULATED TIME RESOLUTION FOR LGADS



#### DATA ANALYSIS FOR THE TIMING PERFORMANCE

#### Constant fraction discrimination (CFD) technique



#### **Self-trigger from the DUTs:**

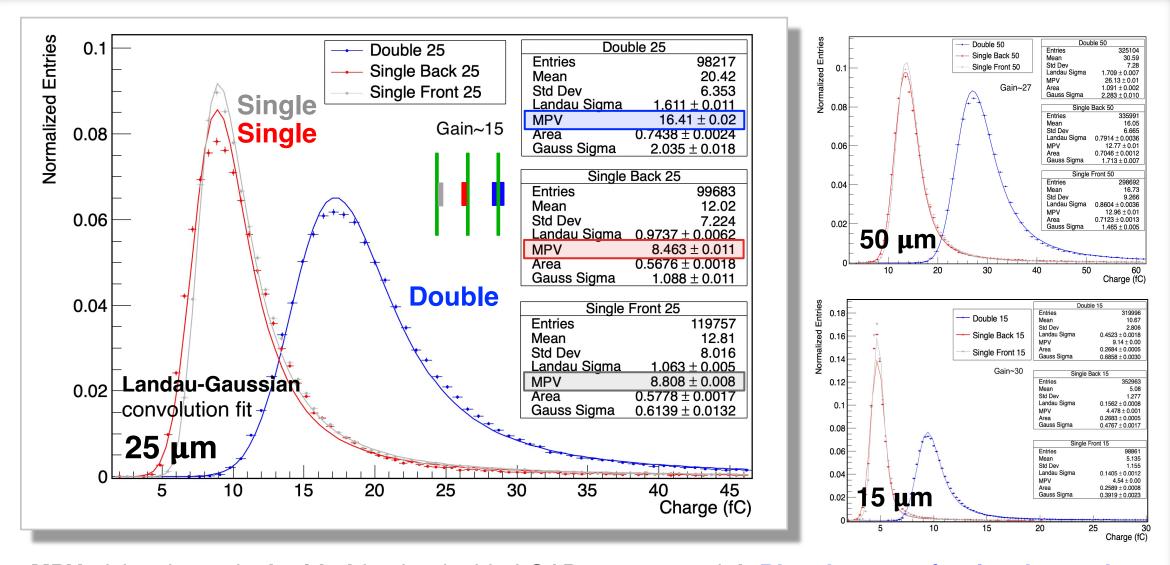
Difference between the threshold crossing time of each couple

#### Asymmetric q-Gaussian fit

- Gaussian shape of the arrival times
- small tails (2.5% of the measurements)

#### **CHARGE DISTRIBUTIONS**



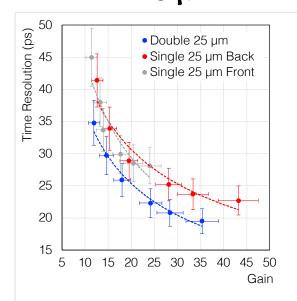


MPV of the charge is **doubled** for the double-LGAD, as expected → Big advantage for the electronics

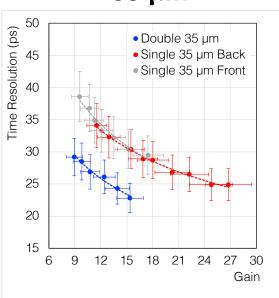


#### Timing performance: Single VS Double-LGAD



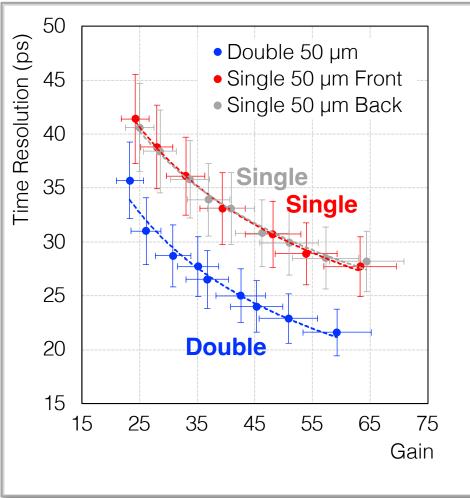


#### 35 μm



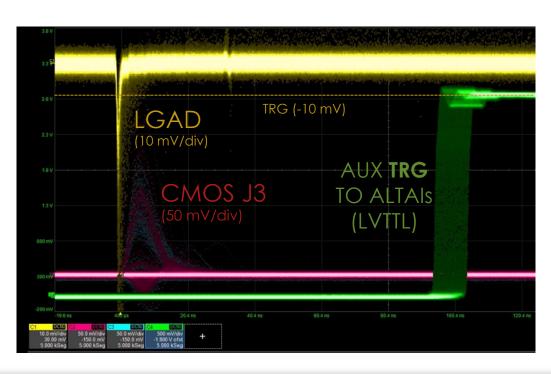
- Single LGADs: comparable time resolution for a similar gain
- Better time resolution for a double-LGAD in respect to single ones

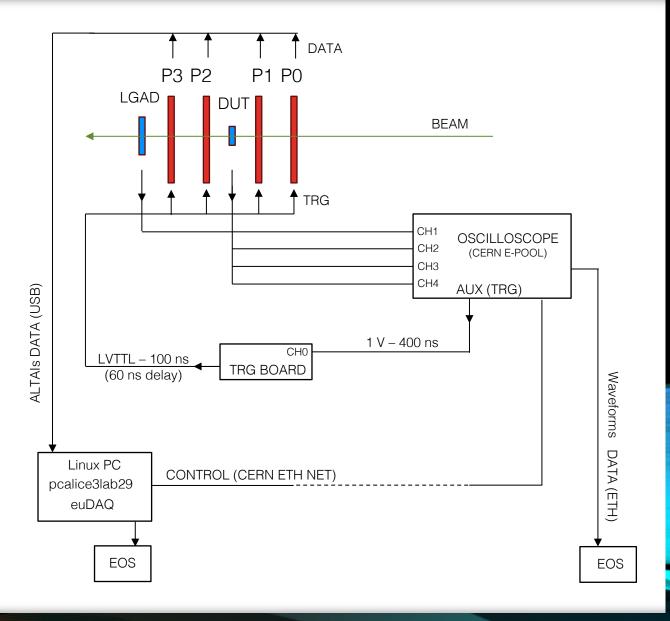
#### 50 μm



#### DAQ/TRG LOGIC WITH THE ALTAI TELESCOPE

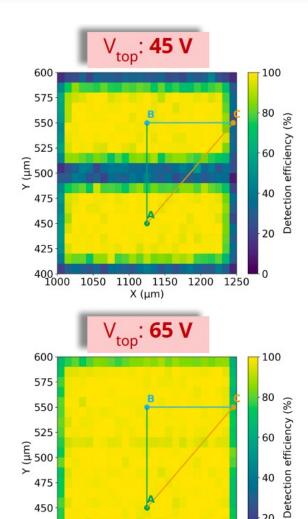
- LGAD and CMOS (DUT) waveforms acquired with an oscilloscope
- Scope AUX TRG signal to ALTAI planes
- ALTAI data acquired with euDAQ
- Syncronization among 2 DAQs checked each 5k triggers (1 scope sequence)





#### **CMOS-LGAD EFFICIENCY**





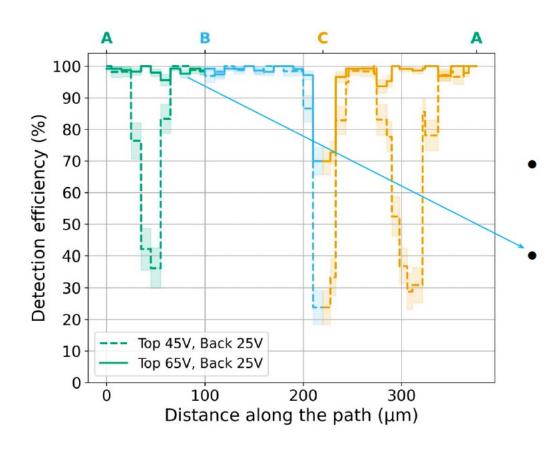
1100 1150 1200 1250

X (µm)

425

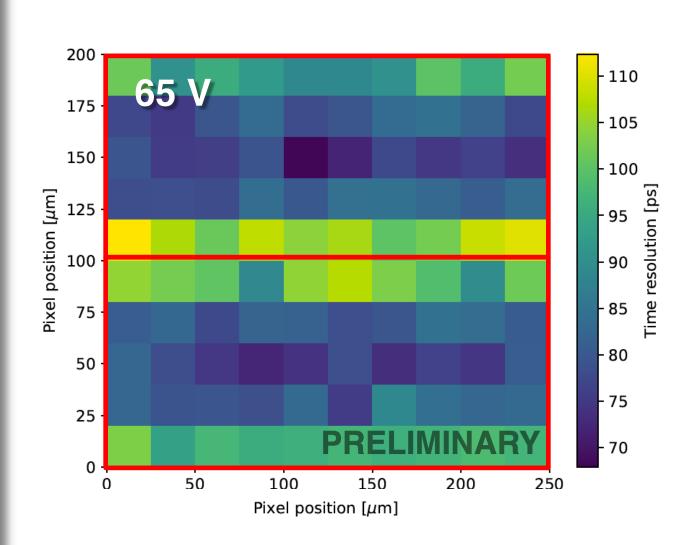
400

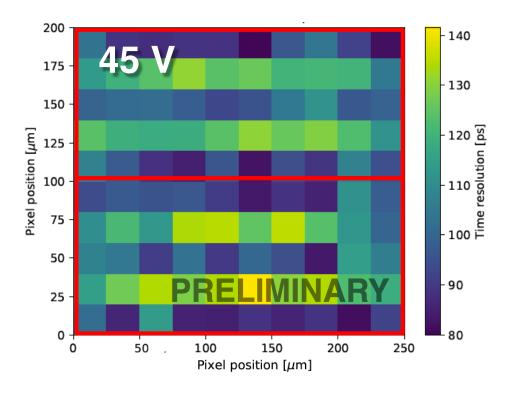
1050



- Detection efficiency improvement increasing the voltage applied at the top electrode
- No significant efficiency drop in between pixels at V<sub>top</sub>: 65V (path A→B)

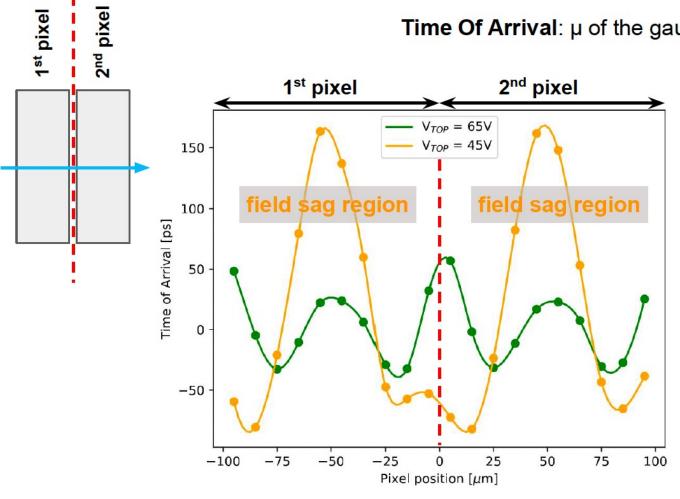
#### **CMOS-LGAD TIME RESOLUTION**





 ◆ At 45V, the time resolution is higher between center and the pixel border (E<sub>field</sub> depletion in the center)

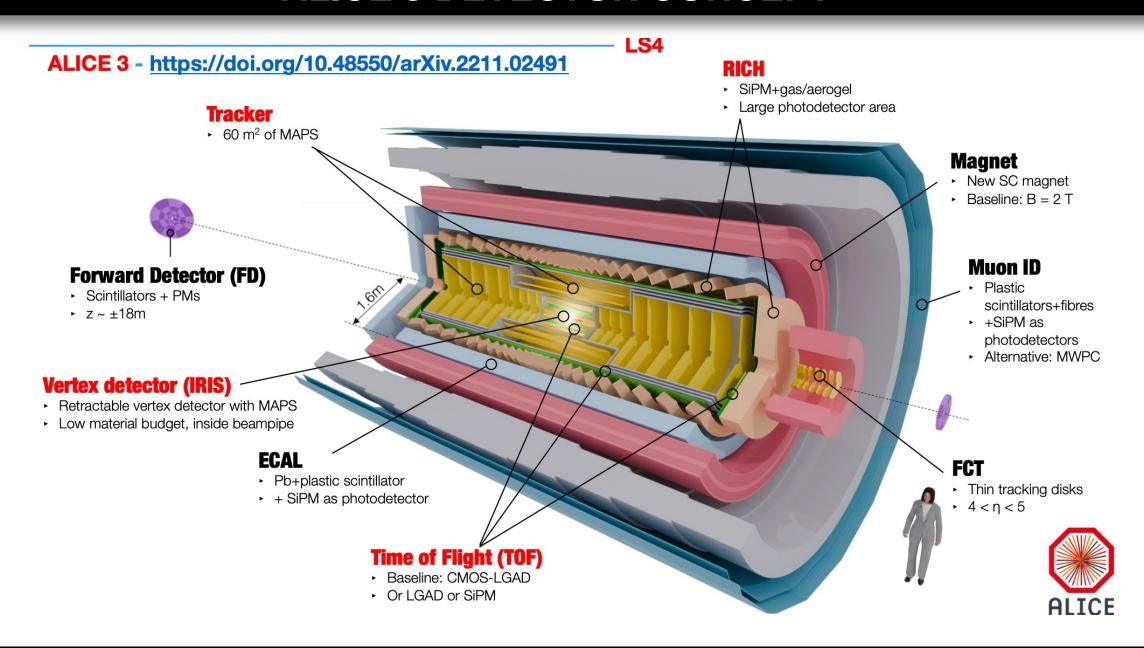
#### **CMOS-LGAD TIME RESOLUTION**



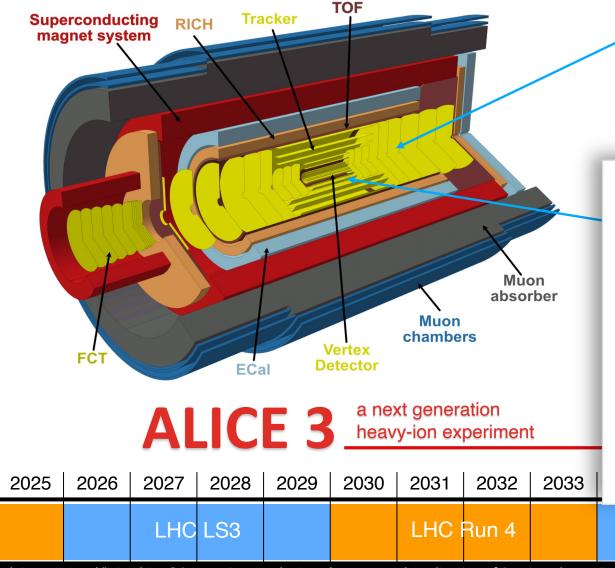
Time Of Arrival: μ of the gaussian fit on the time difference distribution

- Selection of tracks with associated cluster on MADPix
- Time of arrival along the short edge (2x100 µm)
- V<sub>top</sub> 45 V: minimum of electric field in pixel center → field sag region slows down the multiplied charges →delayed signals
  - V<sub>top</sub> 65 V: uniform electric field along the pixel → more stable time response, reduced delay between central and peripheral events

#### **ALICE 3 DETECTOR CONCEPT**



# The ALICE Collaboration has submitted the proposal for a next-generation heavy-ion experiment, ALICE 3, to be installed at the LHC for runs 5 and 6

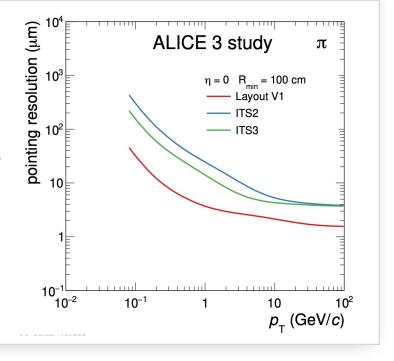


#### **Tracking:**

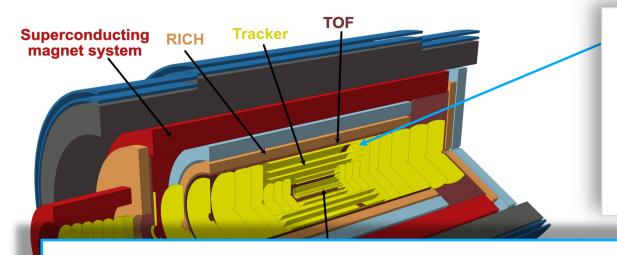
- Excellent resolution on the  $p_T \sim 1-2 \%$
- Large region of pseudorapidity (lηl<4)</li>

#### **Vertexing:**

- First layers
   placed inside
   the beam pipe
- Excellent pointing resolution



## The ALICE Collaboration has submitted the proposal for a next-generation heavy-ion experiment, ALICE 3, to be installed at the LHC for runs 5 and 6

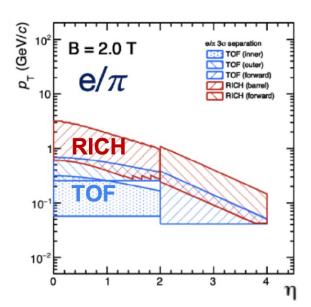


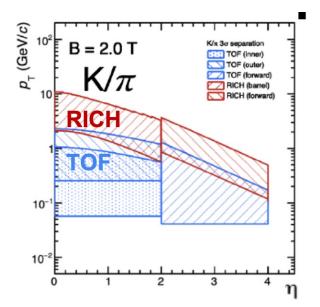
#### **Identification:**

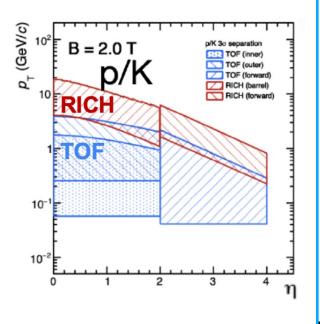
- Particle identification in a very large p<sub>T</sub> range
  - ➤ Hadrons up to 2-3 GeV/c
  - ► Electrons between  $0.05 < p_T < 2 \text{ GeV/}c$
  - ➤ Photons down to very low  $p_T$  (≥1 MeV/c)

Separation (B = 0.5T)  $e/\pi \lesssim 500 \text{ MeV/c}$   $K/\pi \lesssim 2.5 \text{ GeV/c}$   $p/K \lesssim 4 \text{ GeV/c}$ 

TOF + RICH





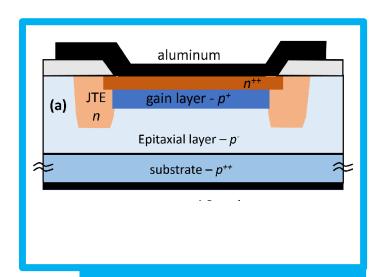


2025

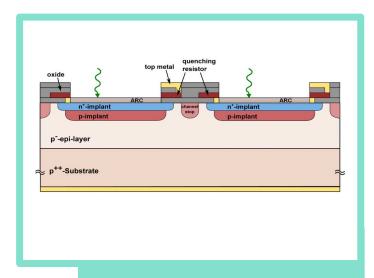
## **TOF SPECIFICATIONS**

	Inner TOF	Outer TOF	Forward TOF Disks
Radius (m)	0.19	0.85	0.15 to 1.0
z range (m)	-0.62 to $0.62$	-3.50 to $3.50$	$\pm 3.70$
Area (m <sup>2</sup> )	1.5	37	6
Acceptance	$ \eta  < 1.9$	$ \eta  < 2$	$2 <  \eta  < 4$
Granularity (mm <sup>2</sup> )	$1 \times 1$	$5 \times 5$	$1 \times 1$ to $5 \times 5$
Hit rate $(kHz/cm^2)$	200	15	280
Material thickness ( $\%X_0$ )	1 to 3	1 to 3	1 to 3
Power density $(mW/cm^2)$	50	50	50
Time resolution (ps)	20	20	20

#### NEW SILICON TECHNOLOGIES

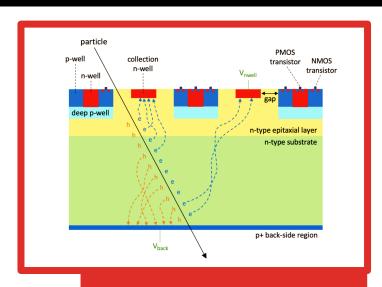


- The possibility of achieving **20 ps has been demonstrated** (potential improv)
- Time res. not affected by different directions of imp. particles



SiPM

- SPAD-based system could merge the TOF and RICH readouts
- The possibility of achieving 20 ps has been demonstrated
- not a viable option for inner TOF and disks (radiation)



**CMOS LGAD** 

- Less material budget and costs
- Simpler and cheaper assembly
- Investigation on innovative designes
  - → required time resolution

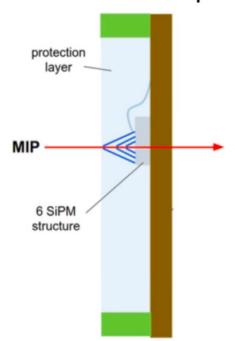
#### SIPM

# Direct detection of charged particles

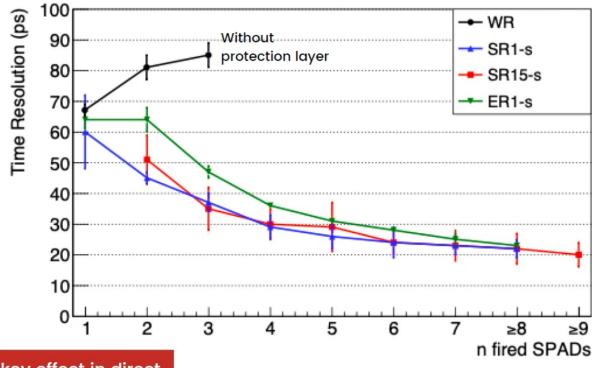
Passage of a charged particle

excess of firing SPADs

CHERENKOV EFFECT whithin the SiPM protection layer



Time resolution @ 4Vov



F. Carnesecchi, B. Sabiu "Measurements of the Cherenkov effect in direct detection of charged particles with SiPMs" (2023) <a href="mailto:arXiv:2305.17762">arXiv:2305.17762</a>